International

SCHOTTKY RECTIFIER

Major Ratings and Characteristics

MBRD650CT MBRD660CT

6 Amp

I_{F(AV)} = 6.0Amp V_R = 50-60V

Units Characteristics Values I_{F(AV)} Rectangular 6 А waveform 50-60 V V_{RRM} I_{FSM} @ tp = 5 µs sine 490 А @3Apk, $T_J = 125^{\circ}C$ V_F 0.65 V (per leg) -40 to 150 °C T_J range

Description/ Features

The MBRD650CT, MBRD660CT surface mount, center tap, Schottky rectifier series has been designed for applications requiring low forward drop and small foot prints on PC board. Typical applications are in disk drives, switching power supplies, converters, free-wheeling diodes, battery charging, and reverse battery protection.

- Popular D-PAK outline
- Center tap configuration
- Small foot print, surface mountable
- Low forward voltage drop
- High frequency operation
- Guard ring for enhanced ruggedness and long term reliability



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MBRD650CT, MBRD660CT

Bulletin PD-20755 rev. E 05/06

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Voltage Ratings

Part number	MBRD650CT	MBRD660CT
V _R Max. DC Reverse Voltage (V)	50	60
V _{RWM} Max. Working Peak Reverse Voltage (V)		

Absolute Maximum Ratings

	Parameters	Value	Units	Conditions	
I _{E(AV)}	Max. Average Forward (Per Leg)	3.0	A	50% duty cycle @ T _c = 128°C, r	ectangular wave form
. (,	Current * See Fig. 5 (Per Device)	6		-	
I _{FSM}	Max. Peak One Cycle Non-Repetitive	490	Α	5µs Sine or 3µs Rect. pulse	Following any rated load condition and with
	Surge Current * See Fig. 7	75		10ms Sine or 6ms Rect. pulse	rated V _{RRM} applied
E _{AS}	Non-Repet. Aval. Energy (Per Leg)	6	mJ	$T_{J} = 25 \degree C, I_{AS} = 1 \text{ Amp}, L = 12 \text{ mH}$	
I _{AR}	Repetitive Avalanche Current	0.6	A	Current decaying linearly to zer	
	(PerLeg)			Frequency limited by $T_J max. V_j$	= 1.5 x V _R typical

Electrical Specifications

	Parameters	Value	Units	Conditions	
V _{FM}	Max. Forward Voltage Drop	0.7	V	@ 3A T ₁ = 25 °C	
1 101	(Per Leg) * See Fig. 1 (1)	0.9	V	@ 6A 1 _J = 23 C	
		0.65	V	@ 3A	
		0.85	V	@ 6A T _J = 125 °C	
I _{RM}	Max. Reverse Leakage Current	0.1	mA	$T_{J} = 25 \text{ °C}$ $V_{p} = \text{rated } V_{p}$	
	(Per Leg) * See Fig. 2 (1)	15	mA	$T_J = 125 \text{ °C}$	
CT	Typ. Junction Capacitance (Per Leg)	145	pF	V_R = 5 V_{DC} (test signal range 100Khz to 1Mhz) 25°C	
L _S	Typical Series Inductance (Per Leg)	5.0	nH	Measured lead to lead 5mm from package body	
dv/dt	Max. Voltage Rate of Change	10000	V/µs	(Rated V _R)	

(1) Pulse Width < 300µs, Duty Cycle <2%

Thermal-Mechanical Specifications

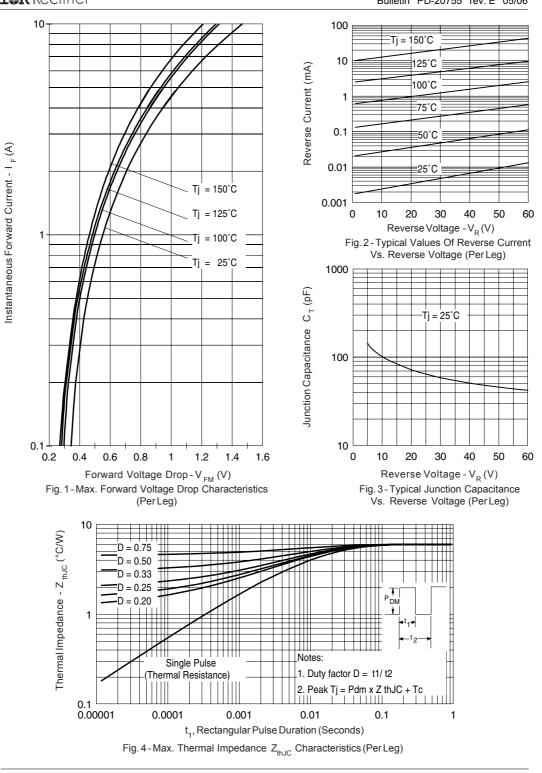
	Parameters		Value	Units	Conditions
TJ	Max. Junction Temperature Range (*)		-40 to 150	°C	
T _{stg}	Max. Storage Temperature Range		-40 to 150	°C	
R_{thJC}	Max. Thermal Resistance	(PerLeg)	6	°C/W	DC operation * See Fig. 4
	Junction to Case	(Per Device)	3		
R _{thJA}	Max. Thermal Resistance J	unction	80	°C/W	
	to Ambient				
wt	Approximate Weight		0.3 (0.01)	g(oz.)	
	Case Style		D-Pa	k	Similar to TO-252AA
	Device Marking		MBRD66	50CT	

 $\frac{(^{*})}{dTj} \frac{dPtot}{dTj} < \frac{1}{Rth(j-a)} \quad \text{thermal runaway condition for a diode on its own heatsink}$

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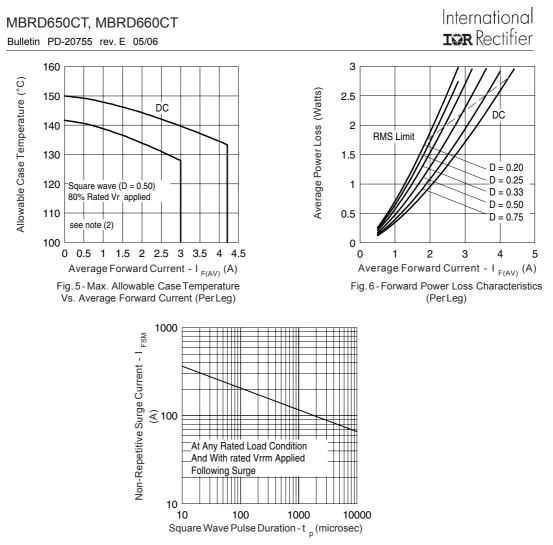


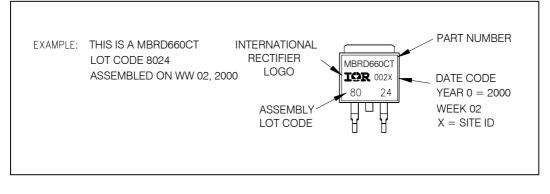
Fig. 7 - Max. Non-Repetitive Surge Current (Per Leg)

(2) Formula used: $T_{C} = T_{J} - (Pd + Pd_{REV}) \times R_{thJC}$; Pd = Forward Power Loss = $I_{F(AV)} \times V_{FM} @ (I_{F(AV)}/D)$ (see Fig. 6); Pd_{REV} = Inverse Power Loss = $V_{R1} \times I_{R} (1 - D)$; $I_{R} @ V_{R1} = 80\%$ rated V_{R}

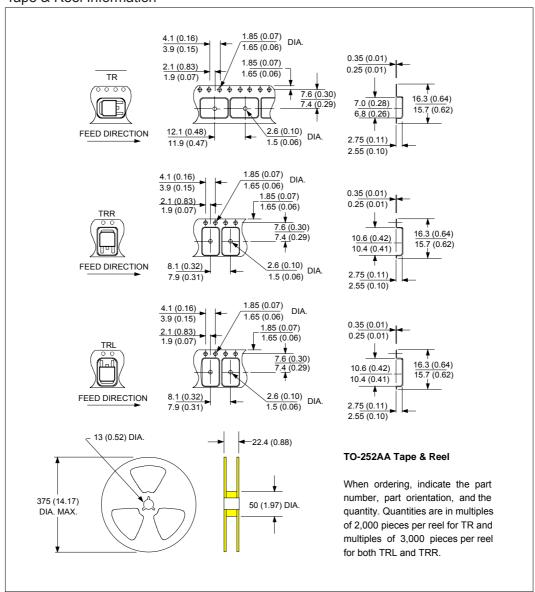
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Outline Table L3 & b3 ES Ç MOLD FLASH SHALL NOT EXCEED .005 [0.13] F BASE WETAL ONLY. D AT DATUM PLANE H. TUNE TO-252AA. NOTATED BOT CH SCALE 201 N C HES .094 .095 .035 .035 .031 .045 .024 .022 .035 .245 -.265 ġ MAx, 2.39 0.13 0.89 0.79 1.14 5.46 0.61 0.56 0.89 6.22 -6.73 Vill, 2,18 -0,64 0,65 0,76 4,95 0,46 0,41 0,46 5,97 5,21 6,35 4,32 2,29 9,40 Min. .086 -.025 .025 .030 .195 .018 .018 .235 .205 .250 .170 L A A1 b b b b b c c1 c2 D D1 E E1 e H L L1 L2 L3 L4 L5 e e1 e2 7 LEAD AS 6 4 6 HEXFET 1.- GATE 2.- DRAIN 3.- SOURC 4.- DRAIN .09 10.41 1.40 2.74 0.51 0.89 -1.14 0' 0' 25' BSC 1.27 1.02 1.52 10* 15* 35* .02 .035 -.045 0 0 25 .050 .040 .060 10* 15* IGBT & CoF 由 ₹ ₿ 1.- GATE 2.- COLLECTOR 3.- EMITTER 4 - COLLECTOR Modified JEDEC outline TO-252AA Dimensions in millimeters and (inches)

Part Marking Information



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Tape & Reel Information

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Device Code	MBR D 6 60 CT TR - 1 2 3 4 5 6 7
	 Schottky MBR Series D = D-Pak (TO-252AA) Currrent Rating (6 = 6A) Voltage Ratings Voltage Ratings CT = Center Tap (Dual) O = 60V Onone = Tube (50 pieces) TR = Tape & Reel TRL = Tape & Reel (Left Oriented) TRR = Tape & Reel (Right Oriented) TRR = Tape & Reel (Right Oriented) O = 000

Ordering Information Table

Data and specifications subject to change without notice. This product has been designed and qualified for AEC Q101 Level. Qualification Standards can be found on IR's Web site.

International

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